

BCY79BP Transistors

Si PNP Lo-Pwr BJT

Military/High-Rel N

$V_{(BR)CEO}$ (V) 45

$V_{(BR)CBO}$ (V)

$I_{(C)}$ Max. (A) 200m

Absolute Max. Power Diss. (W) 400m

Maximum Operating Temp (θC) 175 \bar{o}

$I_{(CBO)}$ Max. (A) 20nx

@ $V_{(CBO)}$ (V) (Test Condition)

$V_{(CE)sat}$ Max. (V)

@ $I_{(C)}$ (A) (Test Condition)

@ $I_{(B)}$ (A) (Test Condition)

$h_{(FE)}$ Min. Current gain. 250

$h_{(FE)}$ Max. Current gain.

@ $I_{(C)}$ (A) (Test Condition) 2.0m

@ $V_{(CE)}$ (V) (Test Condition) 5.0

$f_{(T)}$ Min. (Hz) Transition Freq 180M

@ $I_{(C)}$ (A) (Test Condition)

@ $V_{(CE)}$ (V) (Test Condition)

$C_{(obo)}$ (Max) (F) 4.5p

@ $V_{(CB)}$ (V) (Test Condition)

@Freq. (Hz) (Test Condition)